

RoHS Compliant Product A suffix of "-C" specifies halogen or lead -free

#### DESCRIPTION

SSMG501 is a simple general purpose current regulation component that can be easily used in various LED lighting applications. With the excellent load/line regulation and minimized chip current skew, SSMG501 keep LED's current very stable even when power or load fluctuate in a wide range and make intensity very uniform in large area of LED light source.

Except power supply function, the VDD pin of SSMG501 is output enable (OE) also, and can be used in digital PWM controlled circuit to achieve more precise current adjusting in gray level applications.

The minimized power supply voltage let SSMG501 be used as a current regulative diode (CRD) when VDD and VP pin are tight together. This application makes SSMG501 very easy to be used. Just like a diode, when this diode is inserted in LED series, the current in circuit is regulated.

In high supply voltage and low LED load voltage application, two or more single channel SSMG501 can be connected in series to share redundant high voltage. the extra redundant voltage can be share by each SSMG501 by a reasonable mechanism. This special capability let SSMG501 very suit for the usage of wide range power supply that many liner type LED drivers cannot work.

#### **FEATURES**

- 18mA~30mA constant current regulator
- Self power structure, no extra power supply is needed
- 0.4V~17V output voltage
- 2µS/2µS current rising/falling time
- Cascade-able for higher voltage application
- No external current setting resistor is needed
- 1.6V~12V supply voltage
- PWM dimming by V<sub>DD</sub> pin
- -40°C ~120°C junction operating temperature
- Less than 1%/V load(or line) regulation

## **APPLICATIONS**

- General LED Lighting
- LED back lighting
- LED torch/flashing
- RGB lighting

#### **MARKING CODE**

SSMG501-18: 1A18 SSMG501-20: 1A20 SSMG501-25: 1A25 SSMG501-30: 1A30

Note: 18, 20, 25, 30 = Output Current(mA)

#### PACKAGE INFORMATION

Weight: 0.07800g (Approximately)



DEE	Millimeter		DEE	Millimeter		
KLF.	Min.	Max.	NLF.	Min.	Max.	
A	2.70	3.10	G	0.09	0.18	
В	2.10	3.00	Н	0.45	0.70	
С	1.20	1.80	J	0.08	0.25	
D	0.89	1.40	K	-	-	
E	1.78	2.04	L	0.89	1.02	
F	0.30	0.50				

http://www.SeCoSGmbH.com/



# BLOCK DIAGRAMS PER CHANNEL AND IDEAL $\mathsf{I}_V$ CHARACTERISTICS





#### **TERMINAL DESCRIPTION**

Pin name	Function	Pin #
Vdd	Power supply	2
VP	Current in	1
VN	Current out	3

## ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V <sub>DD</sub>	0 ~ 17	V
Output Voltage	VP	-0.2 ~ 20	V
Output Current	I <sub>PN</sub>	IS** +10%	mA
Power Dissipation	P <sub>D</sub>	250	mW
Thermal Resistance	R <sub>0JA</sub>	300	°C/W
Operating Temperature	T <sub>OPR</sub>	-40 ~ +85	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ +150	°C

#### ELECTRICAL CHARACTERISTICS AND RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Supply Voltage	V <sub>DD</sub>	Room Temp.	1.6	-	12	V
Supply Current	I <sub>DD</sub>	-	100	150	250	μA
		V <sub>DD</sub> =5V, I <sub>P</sub> ≒I <sub>S</sub> **	0.4	-	17	V
Output Voltage	VP	$V_{DD}=3V, I_P = I_S^{**}$	0.45	-	17	V
		$V_{DD}$ =1.7V, $I_P$ $\doteqdot$ $I_S$ **	1.2	-	MAX   12   250   17   17   17   17   17   17   17   17   17   17   17   17   17   17   17   17   17   17   13	V
Output Current	ls	Spec	15	-	30	mA
Leakage	I <sub>Leakage</sub>	$0.4V > V_{DD} > 0V, V_{P}=15V$	1	-	5	μA
Line Regulation	$%N_{DD}$	$12V > V_{DD} > 1.6V$	-	-	±1	%/V
Load Regulation	%/V <sub>P</sub>	10V > V <sub>P</sub> > 1.6V	-	-	±1	%/V
Thermal Regulation	%/10°C	V <sub>DD</sub> =VP=2V	-	-	±0.5	%/10°C
Threshold Voltage	V <sub>iboost</sub>	I <sub>P</sub> =IS*1.1	11	12	13	V
Current Boost	I <sub>boost</sub>	V <sub>P</sub> =Viboost	7	10	13	%* IS

\*\* Is is output saturation current.

# SWITCHING CHARACTERISTICS (T<sub>A</sub> = 25°C)

PARAMETER	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Propagation Delay Time VDD "L" $\rightarrow$ "H"	t <sub>pLH</sub>	VP=1V, VDD=0V→3V	-	1	-	μS
Output Current Rising Time	t <sub>Rise</sub>	VP=1V, VDD=0V→3V	-	1.5	5	μS
Propagation Delay Time VDD "H" $\rightarrow$ "L"	t <sub>pHL</sub>	VP=1V, VDD=3V→0V	-	1	-	μS
Output Current Falling Time	t <sub>Fall</sub>	VP=1V, VDD=3V→0V	-	1.5	5	μS

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Any changes of specification will not be informed individually.



## **TEST CIRCUIT**





# CHARACTERISTIC CURVE











# **APPLICATION CIRCUITS**

• 5V PWM Lighting Application



High Voltage Drop Application



12V Lighting Application



Parallel Application



36V Lighting Application

